National Semiconductor

54F/74F365
Hex Buffer/Driver with TRI-STATE® Outputs

General Description

The 'F365 is a hex buffer and line driver designed to be employed as a memory and address driver, clock driver and bus-oriented transmitter/receiver.

Features

- TRI-STATE buffer outputs
- Outputs sink 64 mA
- Bus-oriented

Ordering Code: See Section 11

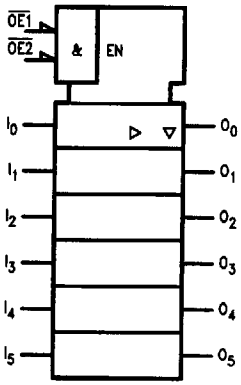
Commercial	Military	Package Number	Package Description
74F365PC		N16E	16-Lead (0.300″ Wide) Molded Dual-In-Line
	54F365DM (Note 2)	J16A	16-Lead Ceramic Dual-In-Line
74F365SC (Note 1)		M16A	16-Lead (0.150″ Wide) Molded Small Outline, JEDEC
	54F365FM (Note 2)	W16A	16-Lead Cerpack
	54F365LM (Note 2)	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C

Note 1: Devices also available in 13″ reel. Use suffix = SCX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

Logic Symbol

IEEE/IEC



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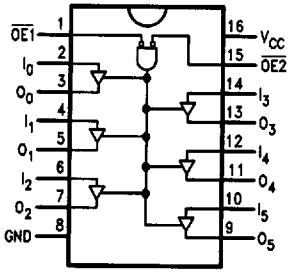
Connection Diagrams

Pin Assignment for DIP, SOIC and Flatpak



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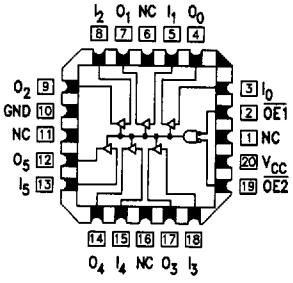
Pin Assignment for LCC



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Unit Loading/Fan Out: See Section 2 for U.L. definitions

Pin Names	Description	54F/74F	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
$\overline{OE}_1$, $\overline{OE}_2$	Output Enable Input (Active LOW)	1.0/0.033	20 μA/20 μA
I_n	Inputs	1.0/0.033	20 μA/20 μA
O_n	Outputs	600/106.6 (80)	−12 mA/64 mA (48 mA)

Function Table

Inputs			Output
$\overline{OE}_1$	$\overline{OE}_2$	I	O
L	L	L	L
L	L	H	H
X	H	X	Z
H	X	X	Z

L = LOW Voltage Level
H = HIGH Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
Plastic	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
TRI-STATE Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Military	−55°C to +125°C
Commercial	0°C to +70°C
Supply Voltage	
Military	+4.5V to +5.5V
Commercial	+4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter		54F/74F Min	54F/74F Typ	54F/74F Max	Units	V_{CC}	Conditions
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	54F 10% V_{CC}	2.4			V	Min	I_{OH} = −3 mA
		54F 10% V_{CC}	2.0					I_{OH} = −12 mA
		74F 10% V_{CC}	2.4					I_{OH} = −3 mA
		74F 10% V_{CC}	2.0					I_{OH} = −15 mA
		74F 5% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	54F 10% V_{CC}			0.55	V	Min	I_{OL} = 48 mA
		74F 10% V_{CC}			0.55			I_{OL} = 64 mA
I_{IH}	Input HIGH Current				20	μA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test				100	μA	0.0	V_{IN} = 7.0V
I_{IL}	Input LOW Current				−20	μA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	μA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	μA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−100		−225	mA	Max	V_{OUT} = 0V
I_{CEX}	Output HIGH Leakage Current				250	μA	Max	V_{OUT} = V_{CC}
I_{ZZ}	Bus Drainage Test				500	μA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			25	35	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			44	62	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			35	48	mA	Max	V_O = HIGH Z

AC Electrical Characteristics: See Section 2 for Waveforms and Load Configurations

Symbol	Parameter	74F $T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			54F T_A, V_{CC} = Mil, $C_L = 50$ pF		74F T_A, V_{CC} = Com, $C_L = 50$ pF		Units	Fig. No.
		Min	Typ	Max	Min	Max	Min	Max		
t_{PLH}	Propagation Delay	2.5	4.6	6.5	2.0	7.0	2.0	7.0	ns	2-3
t_{PHL}	I_n to O_n	2.5	4.9	7.0	2.0	7.0	2.0	7.5		
t_{PZH}	Enable Time	2.5	5.1	9.5	2.0	8.5	2.5	10.0	ns	2-5
t_{PZL}		2.5	5.7	9.0	2.0	8.5	2.5	9.5		
t_{PHZ}	Disable Time	2.0	3.6	6.5	1.5	6.5	2.0	7.0	ns	2-5
t_{PLZ}		2.0	4.4	6.5	1.5	9.0	2.0	7.0		